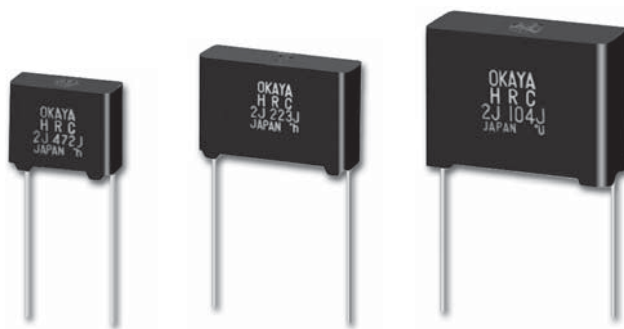


**Features**

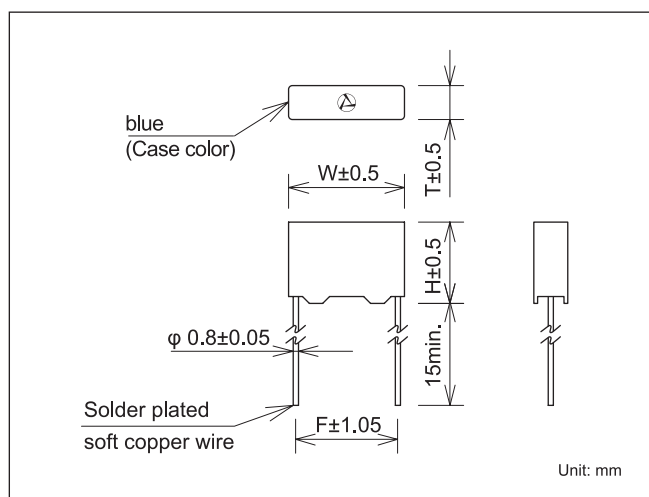
- Best for high frequency and high current.

**Applications**

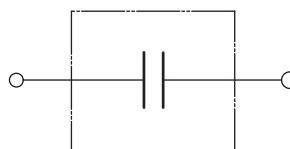
- High frequency resonant circuit, Resonant inverter circuit, Snubber circuit and Protection of semiconductors.



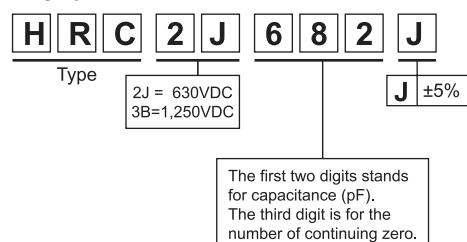
**Dimensions**



**Circuit**



- Model numbering system



**Electrical Specifications**

W.V		2J (630WV)				3B (1250WV)				Dissipation Factor	Test Voltage	Insulation Resistance
Capacitance		Dimensions (mm)				Dimensions (mm)						
PART NO.	μF±5%	W	T	H	F	W	T	H	F			
102	0.001	17.0	5.0	12.0	15.0	17.0	5.0	12.0	15.0	0.001max. (at 1k±100Hz)	WV×1.75 (2~5sec)	50,000MΩmin. (at 20°C 100VDC)
152	0.0015		5.5	12.5			5.5	12.5				
222	0.0022		6.5	13.5			6.5	13.5				
332	0.0033		8.0	15.0			8.0	15.0				
472	0.0047		6.5	16.0			6.5	16.0				
682	0.0068		8.0	17.5			8.0	17.5				
103	0.01	25.0	10.0	19.5	22.5	25.0	10.0	19.5	22.5			
153	0.015		11.0	22.0			11.0	22.0				
223	0.022		12.0	27.5			12.0	27.5				
333	0.033	30.0	11.0	22.0	27.5	30.0	13.5	24.5	27.5			
473	0.047		12.0	27.5			13.5	24.5				
683	0.068	30.0	11.0	22.0	27.5	30.0	16.0	28.0	32.5			
104	0.1		12.0	27.5			16.0	28.0				

Operating Temperature: -40~+85°C